

Field Stop Trench IGBT Die

750 V, 200 A

PCGLA200T75NF8

Features

- AEC-Q101 Rev. D Qualified for Enhanced Reliability
- Maximum Junction Temperature 175°C
- Advanced FS4 Trench Technology
- Positive Temperature Coefficient
- Easy Paralleling
- Short Circuit Rated
- Very Low Saturation Voltage: $V_{CE(SAT)} = 1.45 \text{ V(Typ.) @ } I_C = 200 \text{ A}$
- Optimized for Motor Control Applications

Applications

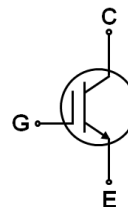
- Automotive Traction Modules
- General Power Modules

MECHANICAL PARAMETERS

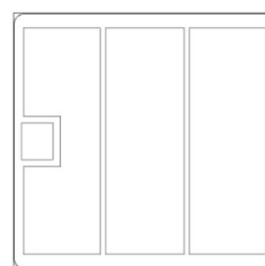
Parameter	Mils	μm
Die Size	394 x 394	10,000 x 10,000
Emitter Pad Size	See chip drawing	See chip drawing
Gate Pad Size	47 x 56	1,200 x 1,430
Scribe Lane Width	3	80
Die Thickness	3.4	86
Top Metal	5 μm AlSiCu	
Back Metal	1.3 μm Al/NiV/Ag	
Topside Passivation	Silicon Nitride plus Polyimide	
Wafer Diameter	200 mm	
Max Possible Die Per Wafer	226	
Recommended Storage Environment	In original container, in dry nitrogen, < 3 months at an ambient temperature of 23°C	

$V_{CES} = 750 \text{ V}$
 $I_C = \text{Limited by } T_{j(\text{max})}$

IGBT DIE



DIE OUTLINE



ORDERING INFORMATION

Device	Inking?	Shipping
PCGLA200T75NF8	Yes	Sawn Wafer on Tape

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ABSOLUTE MAXIMUM RATINGS (T_{VJ}= 25°C Unless Otherwise Noted)

Parameter	Symbol	Ratings	Unit
Collector–Emitter Voltage	V _{CES}	750	V
Gate–Emitter Voltage	V _{GES}	±20	V
DC Collector Current, limited by T _{VJ} max	I _C	(Note 1)	A
Pulsed Collector Current, V _{GE} = 15 V, tp limited by T _{VJ} max (Note 2)	I _{CM}	600	A
Short Circuit Withstand Time, V _{GE} = 15 V, V _{CE} ≤ 400 V, T _{VJ} ≤ 175°C	t _{sc}	4	μs
Operating Junction Temperature	T _{VJ}	–40 to +175	°C
Storage Temperature Range	T _{stg}	–17 to +25	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Depends on the thermal properties of assembly.
2. Not subject to production test – verified by design/characterization.

ELECTRICAL CHARACTERISTICS (T_J= 25°C Unless Otherwise Noted)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
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STATIC CHARACTERISTICS (Tested on wafers)

Collector–Emitter Breakdown Voltage	BV _{CES}	V _{GE} = 0 V, I _C = 1 mA	750	–	–	V
Collector–Emitter Saturation Voltage	V _{CE(SAT)}	I _C = 200 A, V _{GE} = 15 V	–	1.45	1.75	V
Gate–Emitter Threshold Voltage	V _{GE(th)}	V _{GE} = V _{CE} , I _C = 200 mA	4.3	5.5	6.7	V
Collector Cut–off Current	I _{CES}	V _{CE} = V _{CES} , V _{GE} = 0 V	–	–	40	μA
Gate Leakage Current	I _{GES}	V _{GE} = V _{GES} , V _{CE} = 0 V	–	–	±400	nA

ELECTRICAL CHARACTERISTICS (Not subjected to production test – verified by design/characterization)

Collector–Emitter Breakdown Voltage	BV _{CES}	V _{GE} = 0 V, I _C = 1 mA	T _{VJ} = –40°C	700	820	–	V
Collector Cut–off Current	I _{CES}	V _{CE} = V _{CES} , V _{GE} = 0 V	T _{VJ} = 150°C	–	0.2	–	mA
			T _{VJ} = 175°C	–	1.5	–	
Collector–Emitter Saturation Voltage	V _{CE(SAT)}	I _C = 200A, V _{GE} = 15 V	T _{VJ} = 150°C	–	1.65	–	V
			T _{VJ} = 175°C	–	1.7	–	
Input Capacitance	C _{IES}	V _{CE} = 25 V, V _{GE} = 0 V, f = 1 MHz		–	19900	–	pF
Output Capacitance	C _{OES}			–	374	–	pF
Reverse Transfer Capacitance	C _{RES}			–	64	–	pF
Internal Gate Resistance	R _G	f = 1 MHz		–	10	–	Ω
Total Gate Charge	Q _{G(Total)}	V _{CE} = 400 V, I _C = 200 A, V _{GE} = –8 V to +15 V		–	718	–	nC
Gate–Emitter Charge	Q _{GE}			–	385	–	
Gate–Collector Charge	Q _{GC}			–	152	–	
Turn–On Delay Time	t _{d(on)}	V _{CE} = 400 V, I _C = 200 A, R _G = 2 Ω, V _{GE} = ±15 / –8 V, Inductive Load, T _{VJ} = 25°C		–	257.0	–	nS
Rise Time	t _r			–	202.0	–	
Turn–Off Delay Time	t _{d(off)}			–	247.5	–	
Fall Time	t _f			–	163.0	–	
Turn–On Delay Time	t _{d(on)}	V _{CE} = 400 V, I _C = 200 A, R _G = 2 Ω, V _{GE} = ±15 / –8 V, Inductive Load, T _{VJ} = 150°C		–	273.5	–	nS
Rise Time	t _r			–	214.5	–	
Turn–Off Delay Time	t _{d(off)}			–	280.5	–	
Fall Time	t _f			–	247.5	–	

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ELECTRICAL CHARACTERISTICS ($T_J = 25^\circ\text{C}$ Unless Otherwise Noted) (continued)

Parameter	Symbol	Test Conditions	Min.	Typ.	Max.	Unit
ELECTRICAL CHARACTERISTICS (Not subjected to production test – verified by design/characterization)						
Turn-On Delay Time	$t_{d(on)}$	$V_{CE} = 400\text{ V}$, $I_C = 200\text{ A}$, $R_G = 2\ \Omega$, $V_{GE} = \pm 15 / -8\text{ V}$, Inductive Load, $T_{VJ} = 175^\circ\text{C}$	–	282.0	–	nS
Rise Time	t_r		–	227.0	–	
Turn-Off Delay Time	$t_{d(off)}$		–	289.0	–	
Fall Time	t_f		–	269.0	–	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

Switching characteristics and thermal properties are depending strongly on module design and mounting technology.

For ordering, technique and other information on **onsemi** automotive bare die products, please contact automotivebaredie@onsemi.com.

Die Layout

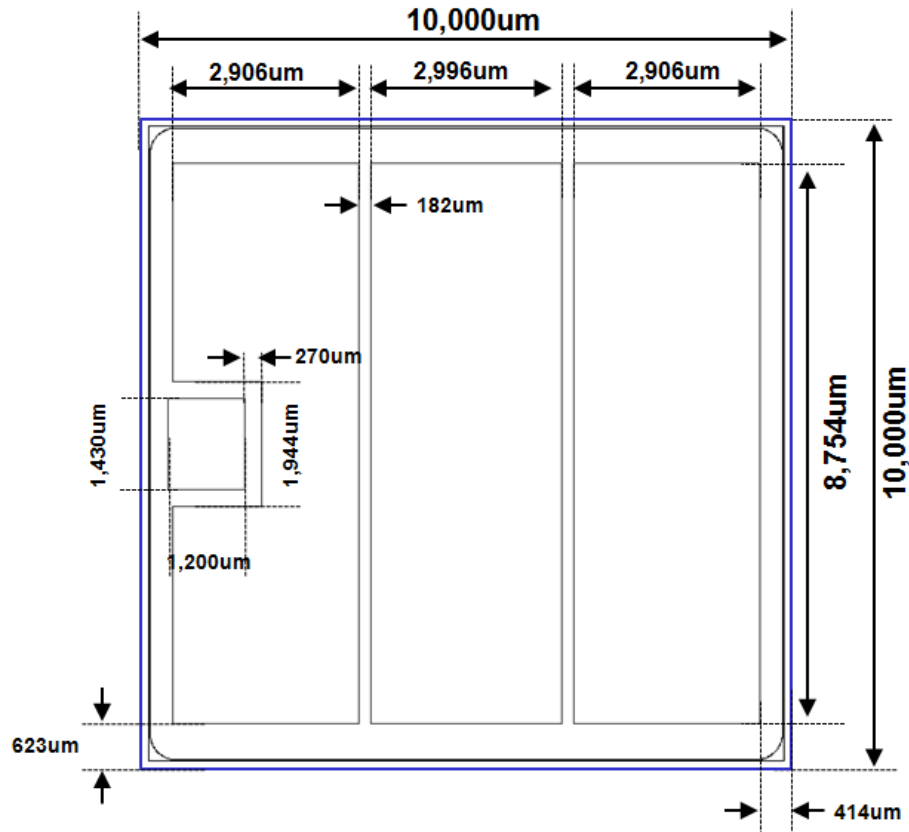


Figure 1. Die Layout

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